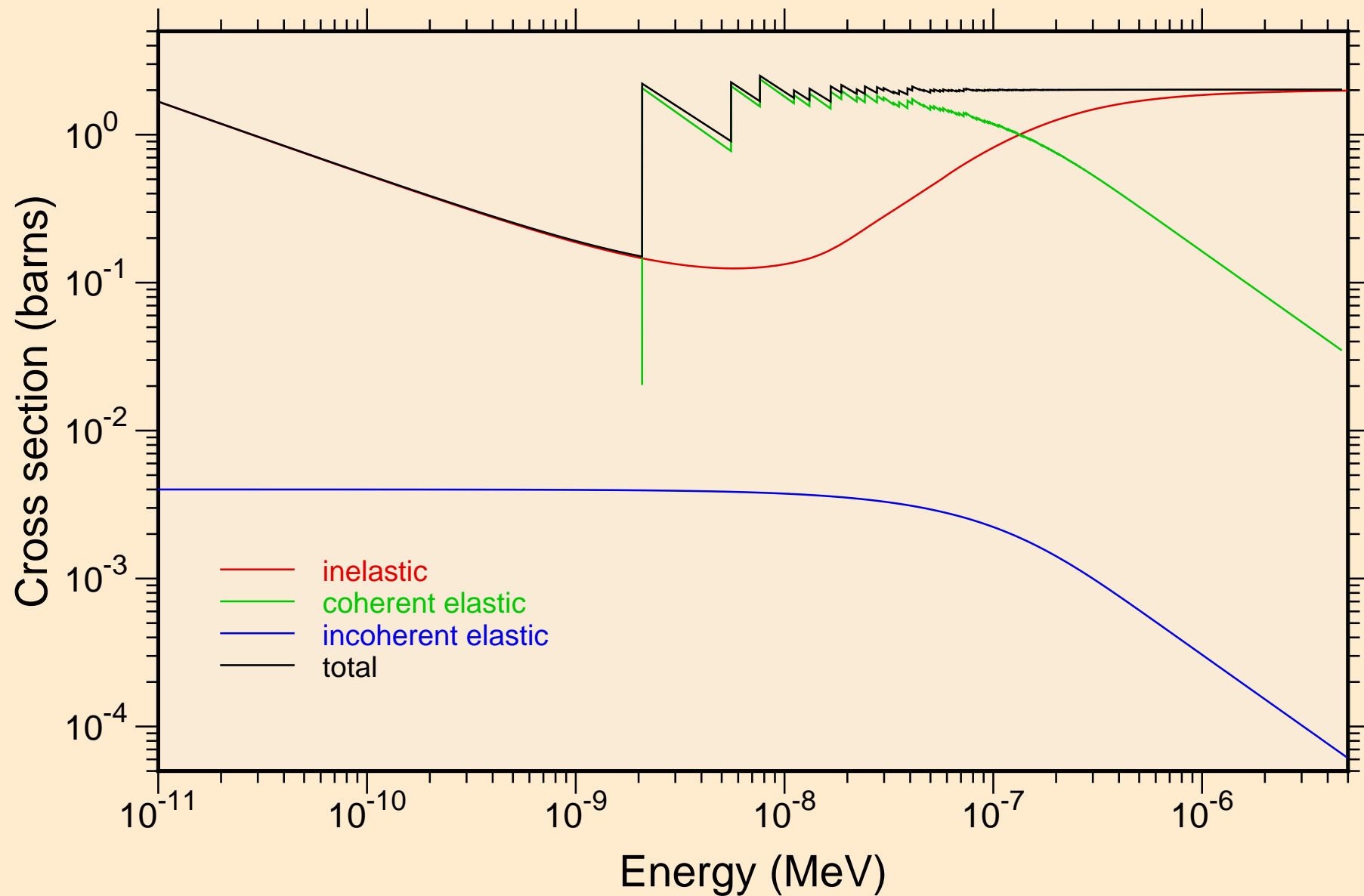
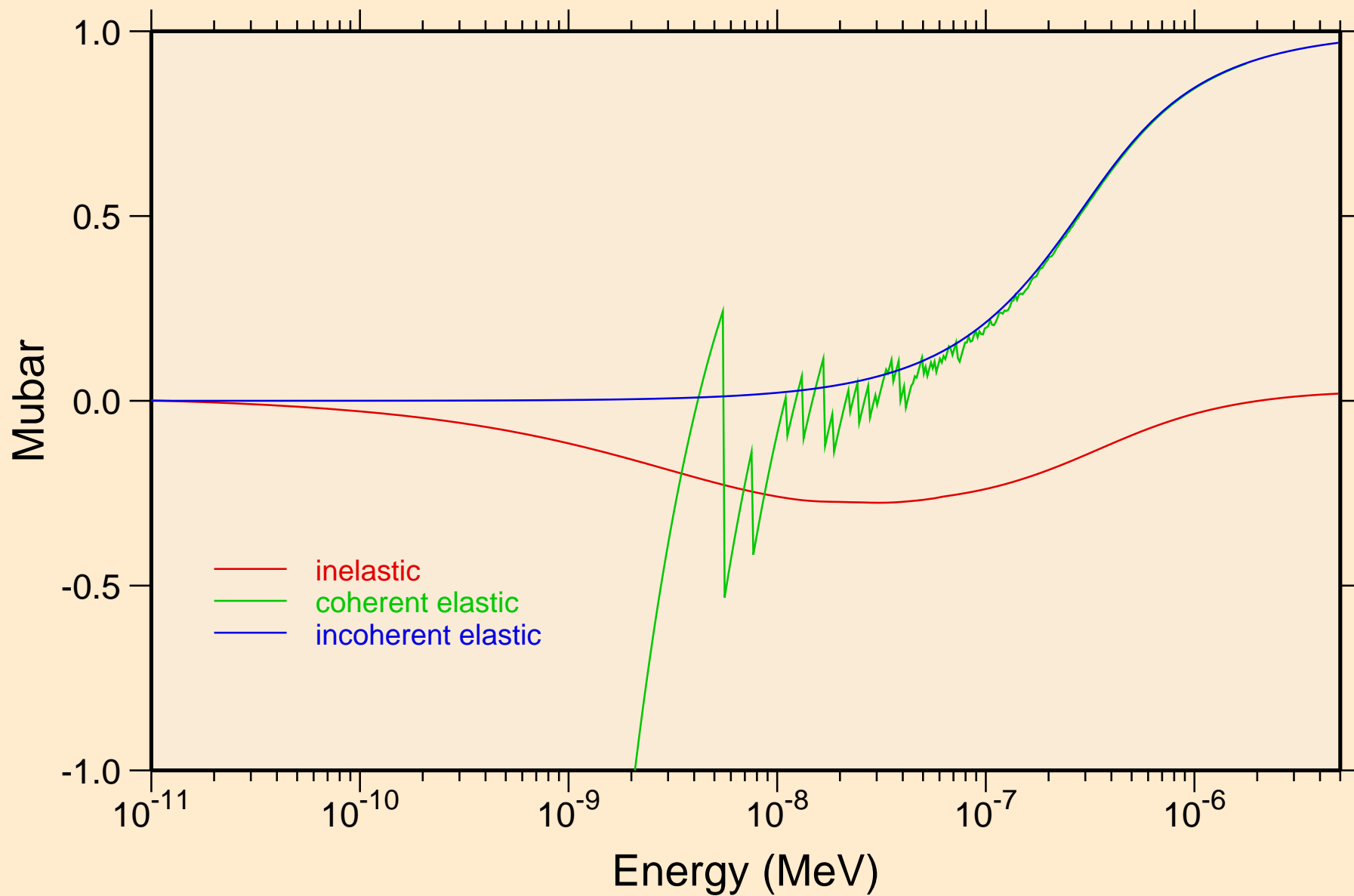


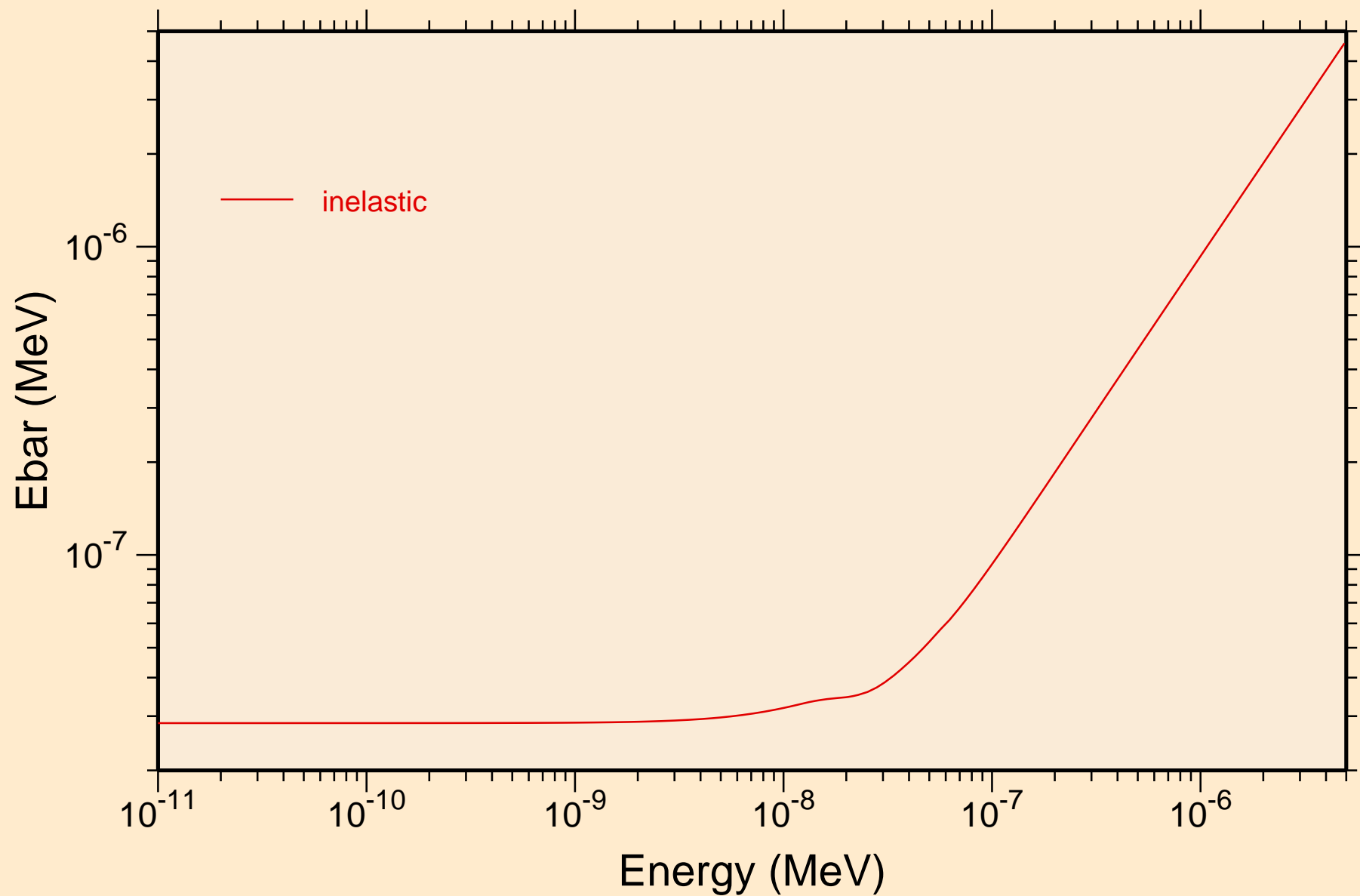
SI-SI_SG227_SILICON @ 293.60K
Thermal cross sections



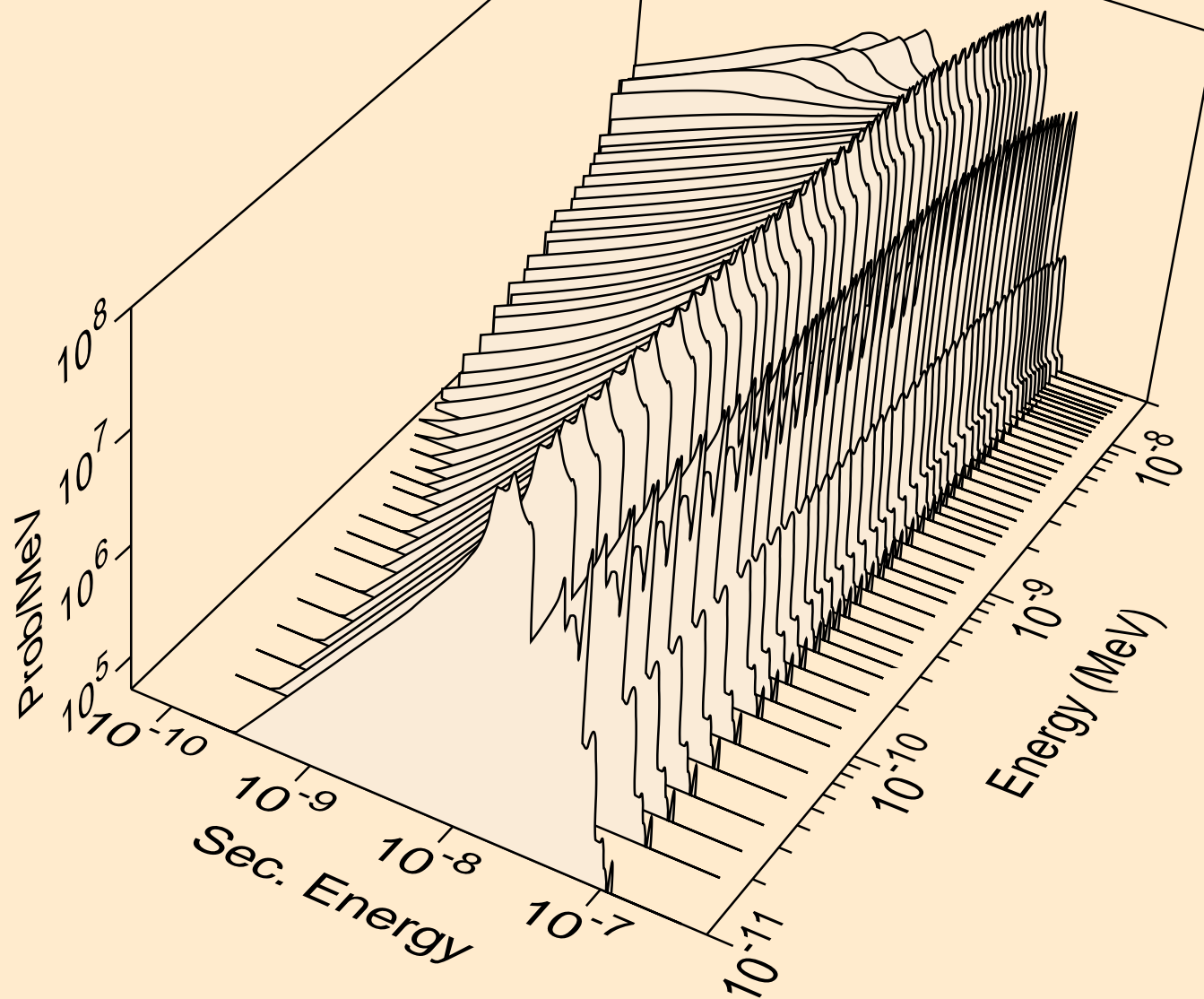
SI-SI_SG227_SILICON @ 293.60K
Thermal mubar



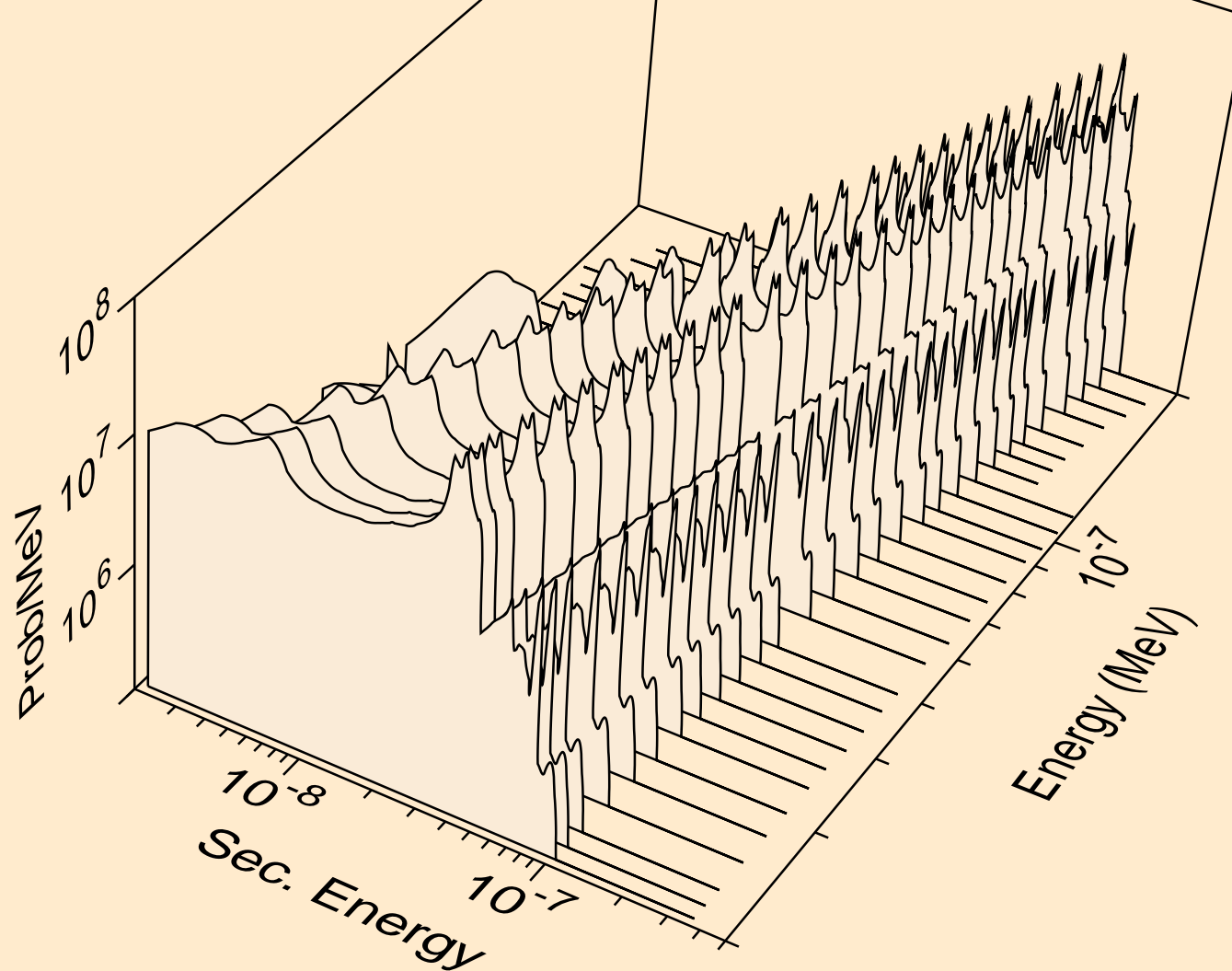
SI-SI_SG227_SILICON @ 293.60K
Thermal ebar



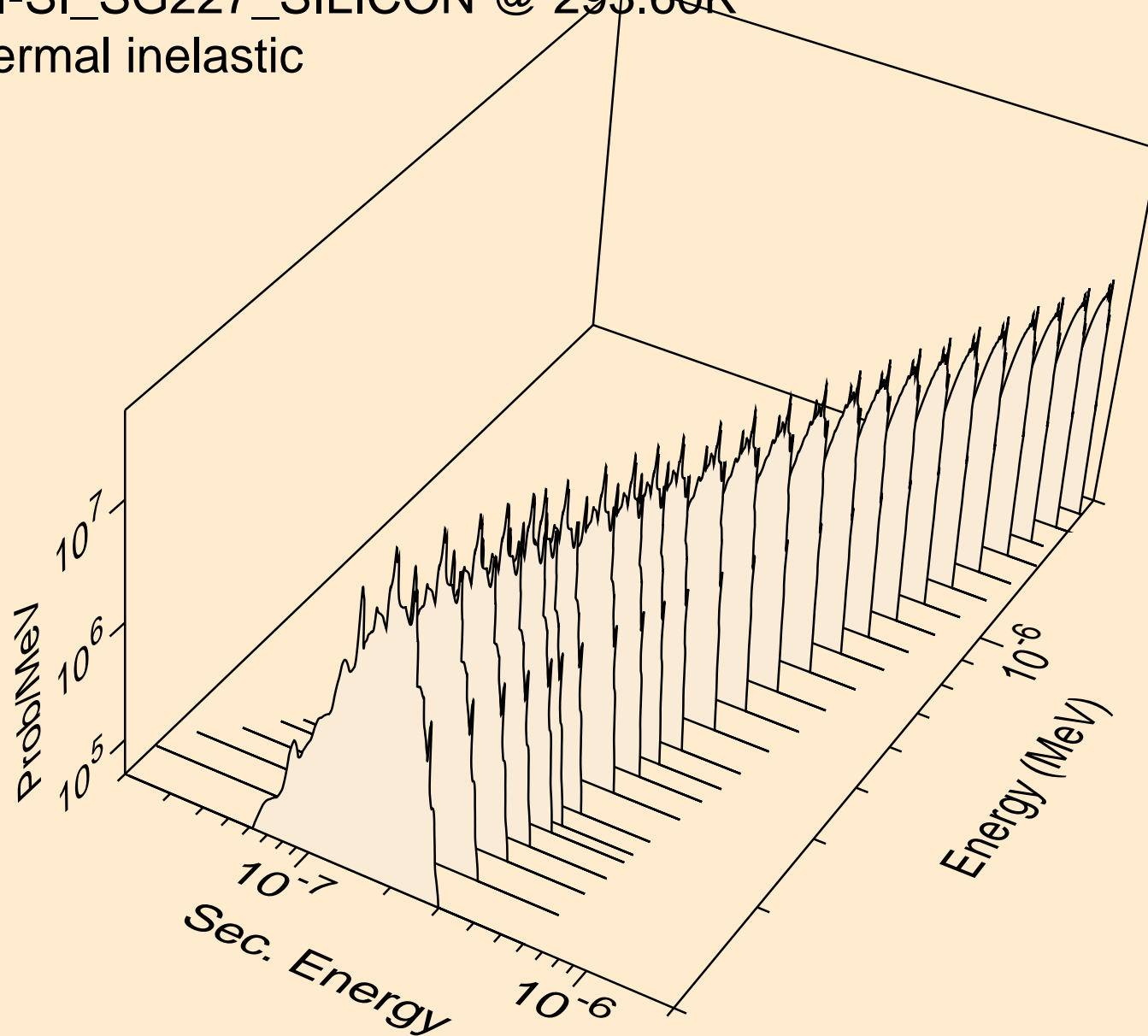
SI-SI_SG227_SILICON @ 293.60K
thermal inelastic



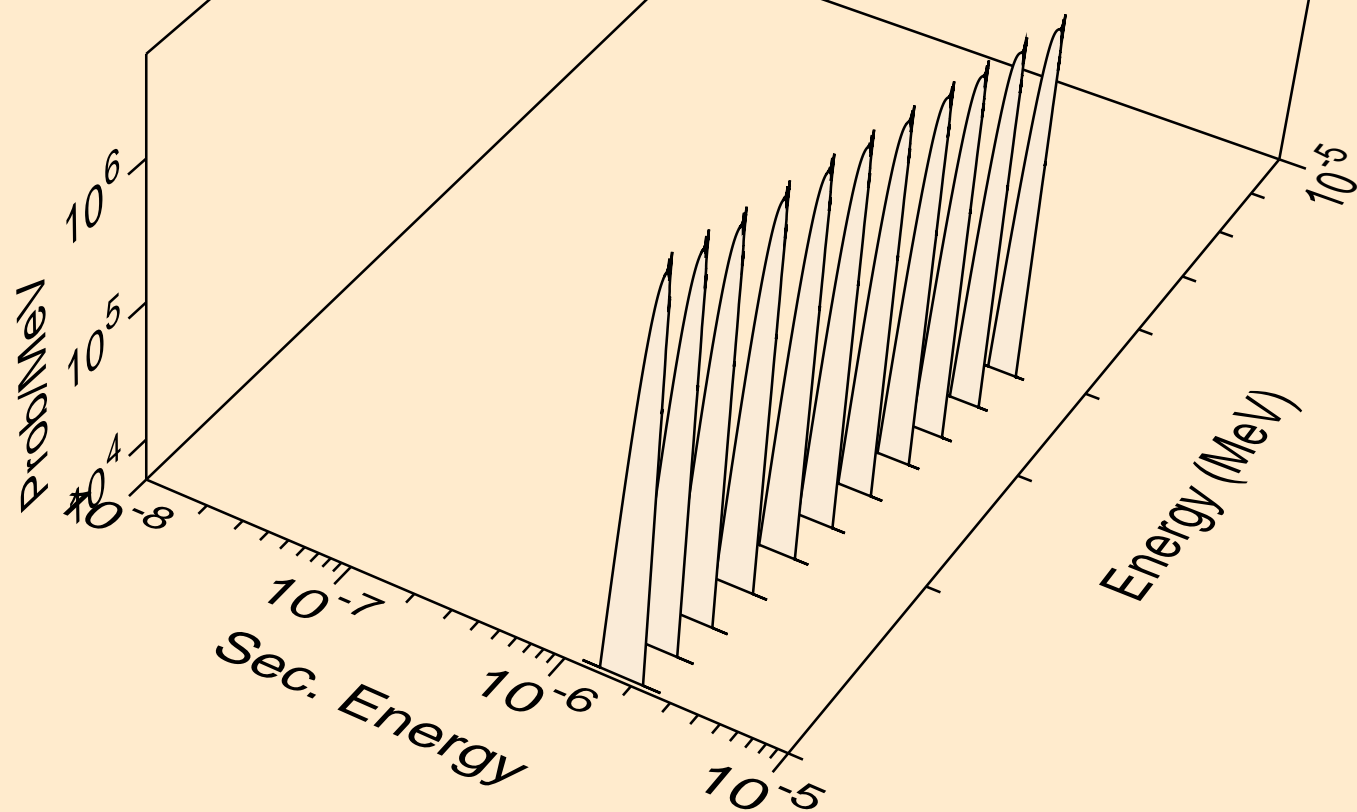
SI-SI_SG227_SILICON @ 293.60K
thermal inelastic



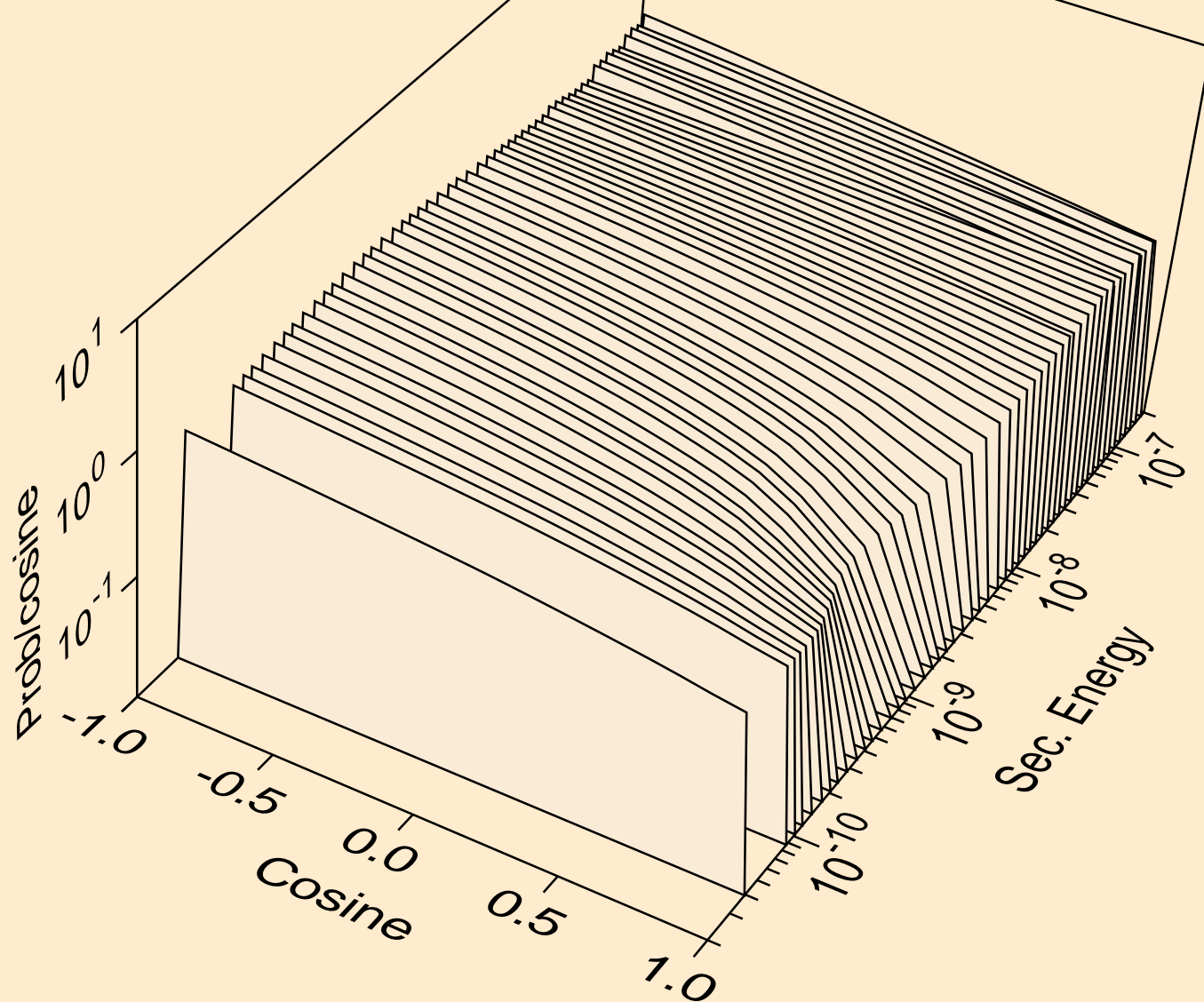
SI-SI_SG227_SILICON @ 293.60K
thermal inelastic



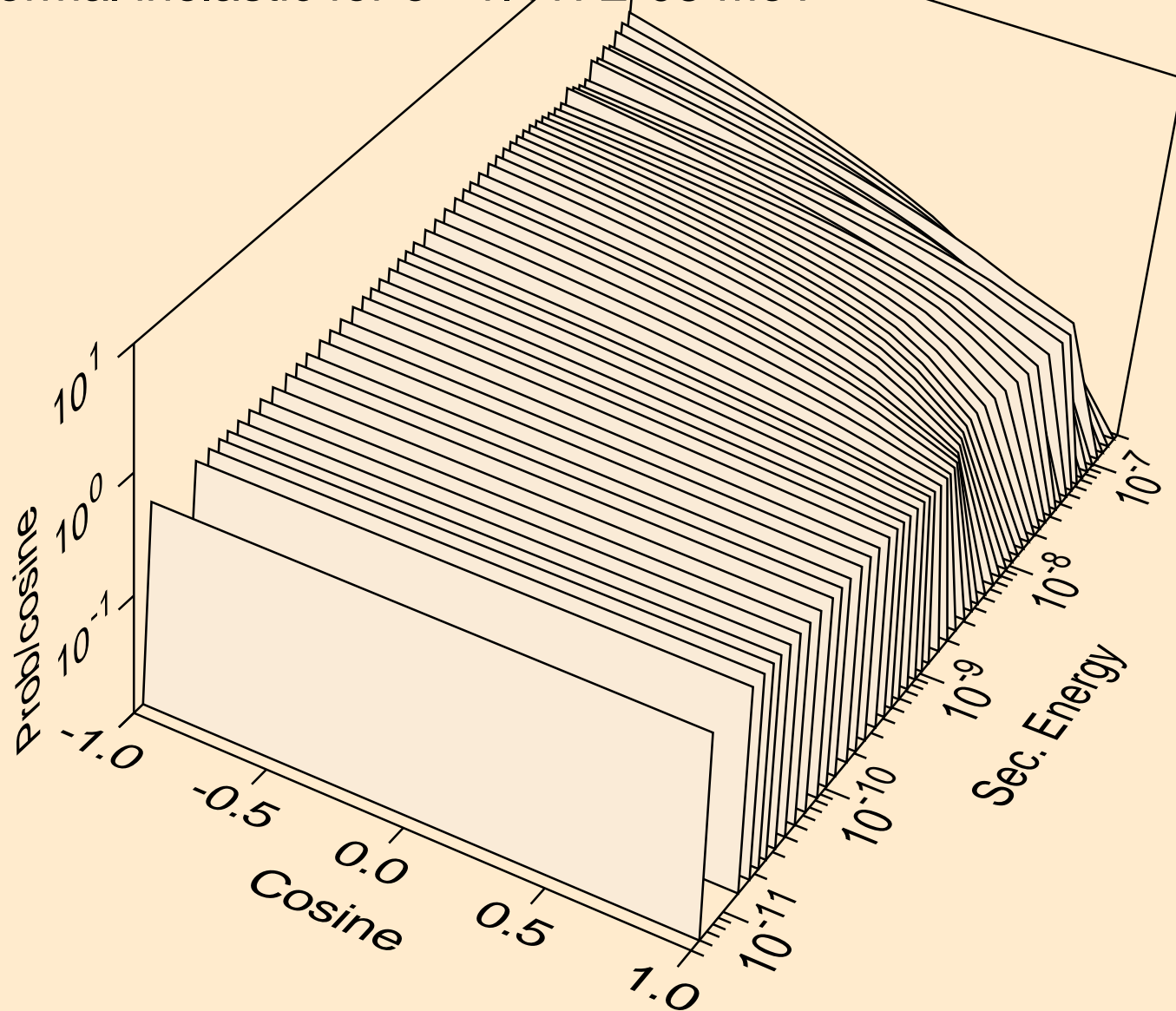
SI-SI_SG227_SILICON @ 293.60K
thermal inelastic



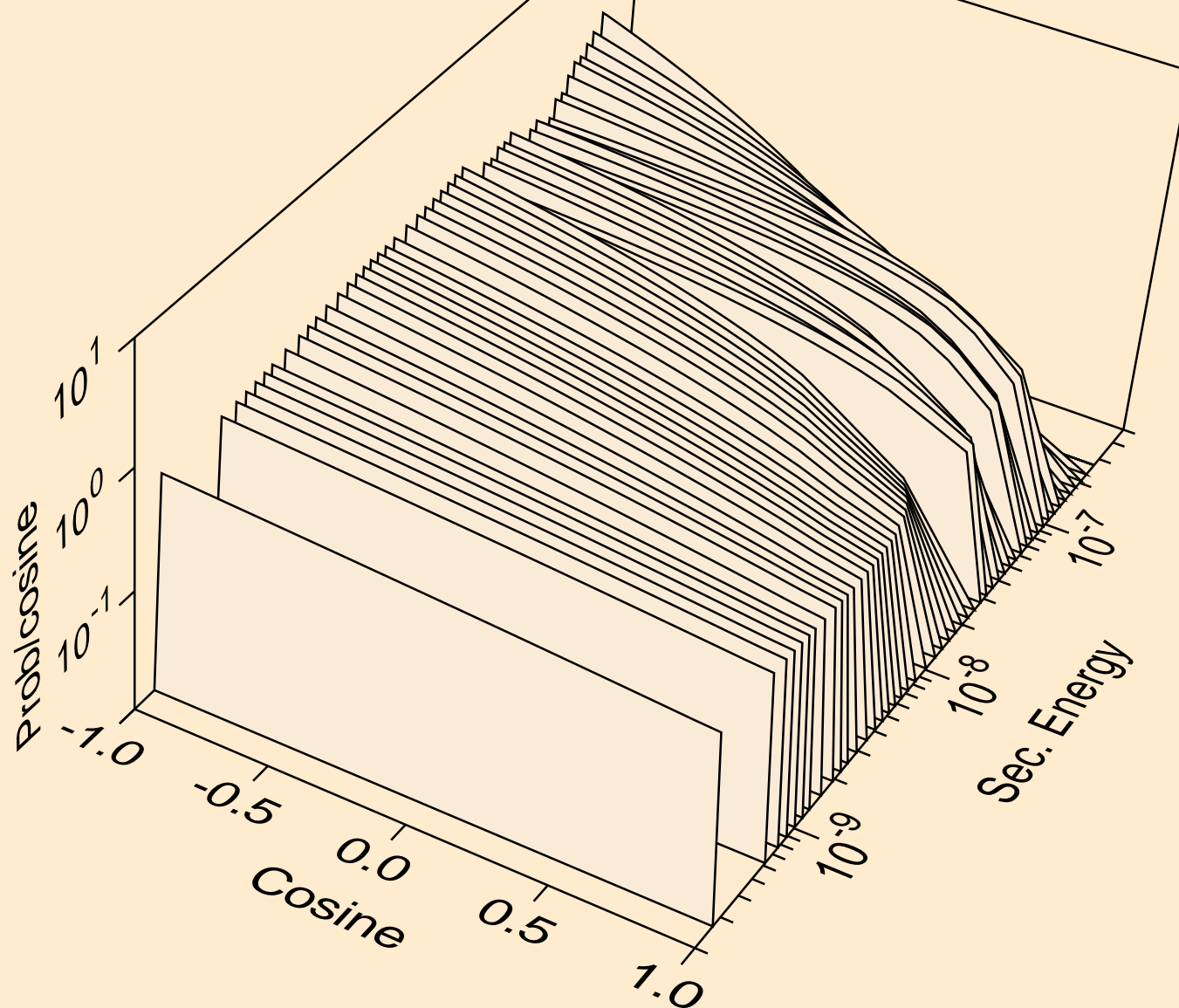
SI-SI_SG227_SILICON @ 293.60K
thermal inelastic for e= 1.012E-09 MeV



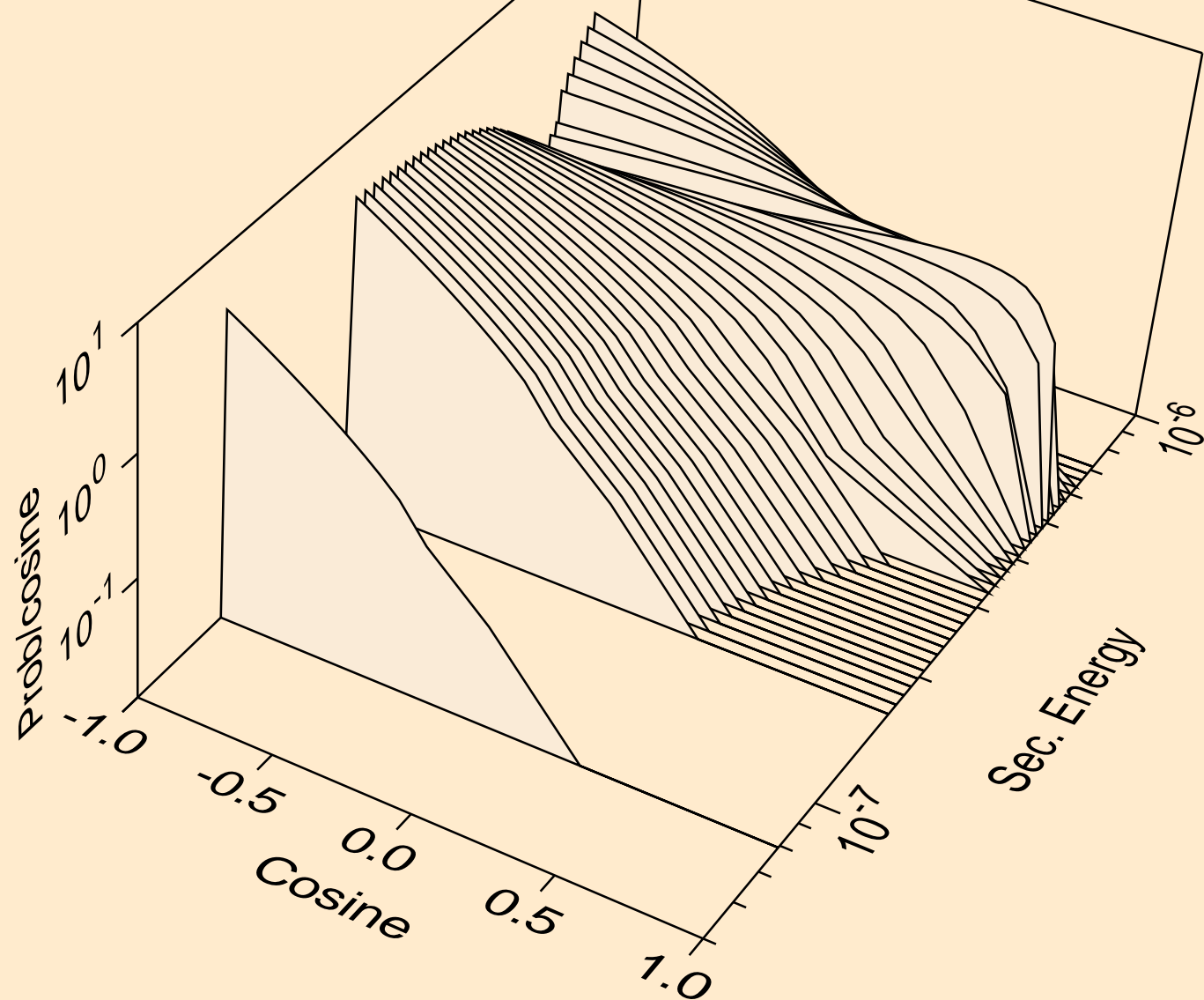
SI-SI_SG227_SILICON @ 293.60K
thermal inelastic for $e = 1.417\text{E-}08$ MeV



SI-SI_SG227_SILICON @ 293.60K
thermal inelastic for e= 9.000E-08 MeV



SI-SI_SG227_SILICON @ 293.60K
thermal inelastic for $e = 5.033\text{E-}07$ MeV



SI-SI_SG227_SILICON @ 293.60K
thermal inelastic for e= 4.070E-06 MeV

